## NSN 5962-01-211-4664

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-211-4664 **Body Length:** 1.000 inches **Body Width:** 0.310 inches **Body Height:** 0.098 inches **Maximum Power Dissipation Rating:** 1.0 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **End Application:** 4aircraft, f-16; aircraft, galaxy c-5; support equipment, b-1 aircraft, ballistic missile early warning sts (bmews); pave phased array warning system (paws); aircraft, stratolifter c-135; over the horizon back scanner (oth-b) program (an/fps-118) **Features Provided:** High performance and static operation and 3-state output **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** N-type metal oxide-semiconductor logic **Input Circuit Pattern:** 18 input **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** 5.5 volts power source **Memory Device Type:** Ram **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 20 printed circuit Shelf Life: N/a **Unit Of Measure:** 

Fiig:

A458a0

**Demilitarization:** Yes - demil/mli